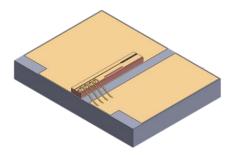
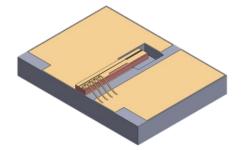


# Specification Sheet | 823 nm Series

Distributed Bragg Reflector (DBR) Laser Diode



Chip on Submount (CoS)



CoS + Mode-Hop Free (MHF)

### **Description**

The 823 nm DBR Series of high-performance edge-emitting laser diodes are based on Photodigm's advanced monolithic single-frequency Gallium Arsenide (GaAs) based laser technology. It provides a single spatial mode beam and has passivated facets for reliability. The 823 nm Series DBR devices are used as low-noise pump sources for biomedical diagnostics and imaging applications.

### 823 nm DBR Chip on Submount (CoS) Characteristics

	Chip Architecture
Parameters <sup>1</sup>	High Power
Wavelength, Nominal (nm) <sup>2</sup>	823 ± 0.6
Power Range (mW)	80–180
Operating Current, Max (CW & Pulsed) (mA)	250
Optical Power at Max Operating Current (mW)	180
Slope Efficiency, Nominal (W/A)	0.85
Threshold Current, Nominal (mA)	50

<sup>1.</sup> Characteristics at T<sub>C</sub> = 25 °C unless otherwise specified. Operating outside of these parameters voids warranty.

## **Available Free-Space Package Add-ons**



TO-8



C-Mount



Transmitter Optical Subassembly (TOSA)

<sup>2.</sup> Hermetically sealed packages may contain CoS that are  $\pm$  1.2 nm from nominal.





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## **Specifications**

#### Laser

Parameter	Unit	Min	Typical	Max
Storage Temperature	°C	0	-	70
Operating Temperature at case	°C	5	-	70
Operating Temperature at laser chip <sup>1</sup>	°C	5	-	45
Laser Series Resistance	Ω	-	2	-
Laser Forward Voltage @ LIV Current	V	-	2	-
Nominal Laser Linewidth @ LIV Current	kHz	-	500	-
Beam Divergence @ FWHM ( $\theta_{  } x \theta_{\perp}$ )	ō	-	6 x 28	8 x 32
Side Mode Suppression Ratio (SMSR)	dB	-	-40	-
Polarization Extinction Ratio	dB	-17	-20	-
Laser Polarization	TE			
Mode Structure	Fundamental Mode			
Temperature Tuning Rate	nm/°C	-	0.06	-
Current Tuning Rate	nm/mA	-	0.002	-
Laser Reverse Voltage	V	-	-	0

<sup>1.</sup> Operation below dew point not recommended without hermetically sealed packaged

### **Free-Space Package Add-Ons**

Parameter	Unit	Min	Typical	Max
Photodiode Forward Current	mA	-	-	10
Photodiode Reverse Voltage	V	-	-	50
TEC Current (TOSA)	A	-1.1	-	1.1
TEC Voltage (TOSA)	V	-3.0	-	3.0
TEC Current (TO-8)	A	-1.8	-	1.8
TEC Voltage (TO-8)	V	-2.2	-	2.2
Thermistor Resistance	kΩ	-	10	-

# **Handling Precautions**

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.





Photodigm, Inc. reserves the right to make changes in design, specifications, and other information at any time, and without prior notice. The information contained within the specification sheet is believed to be accurate. However, no responsibility is assumed for possible inaccuracy or omission. Any information contained herein shall not legally bind Photodigm, Inc. unless it is specifically incorporated in the terms and conditions of a sales agreement.



# Specification Sheet | 823 nm Series

Distributed Bragg Reflector (DBR) Laser Diode

### Air Wavelength Characteristics at Constant Current by Temperature

